

GP20A - GP20M

AXIAL LEADED SILICON RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V

CURRENT: 2.0 A

Features

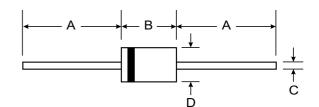
- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: D O 1 5
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number







| DO-15 | | | | | | | | |
|----------------------|-------|-------|--|--|--|--|--|--|
| Dim | Min | Max | | | | | | |
| Α | 25.40 | — | | | | | | |
| В | 5.50 | 7.62 | | | | | | |
| С | 0.686 | 0.889 | | | | | | |
| D | 2.60 | 3.60 | | | | | | |
| All Dimensions in mm | | | | | | | | |

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic | Symbol | GP20A | GP20B | GP20D | GP20G | GP20J | GP20K | GP20M | Unit |
|---|--------------------|-------------|-------|-------|-------|-------|-------|-------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm Vrwm Vr | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | VR(RMS) | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current (Note 1) $@T_A = 75^{\circ}C$ | ю | 2.0 | | | | | | А | |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | IFSM | 70 | | | | | A | | |
| Forward Voltage $@I_F = 2.0A$ | Vfm | 1.0 | | | | | | V | |
| Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$ | Irm | 5.0 50 | | | | | | μA | |
| Typical Junction Capacitance (Note 2) | Cj | 20 | | | | pF | | | |
| Typical Thermal Resistance Junction to Ambient (Note 1) | R ∂ JA | 40 | | | | K/W | | | |
| Operating Temperature Range | Tj | -65 to +125 | | | | | °C | | |
| Storage Temperature Range | Tstg | -65 to +150 | | | | | °C | | |

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.



